NSN 5962-01-234-3569

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View Online at https://aerobasegroup.com/nsn/5962-01-234-3569

Body Length: 1.485 inches Body Width: Between 0.590 inches and 0.625 inches Body Height:

0.217 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Alq176 mlv

Features Provided:

Hermetically sealed and burn in and w/enable and ultraviolet erasable and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

17 input

Current Rating Per Characteristic:

50.00 milliamperes total supply

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

6.5 volts power source

Time Rating Per Chacteristic:

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level

output

Memory Device Type:

Prom

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A458a0

